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Vishay Siliconix

Automotive N-Channel 40 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	40				
$R_{DS(on)}(\Omega)$ at $V_{GS} = 10 \text{ V}$	0.00100				
I _D (A)	200				
Configuration	Single				
Package	TO-263-7L				

FEATURES

- TrenchFET® power MOSFET
- Package with low thermal resistance
- 100 % R_q and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



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N-Channel MOSFET) S

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)					
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	40	V	
Gate-source voltage		V _{GS}	± 20		
Continuous drain current ^a	T _C = 25 °C	I _D	200		
	T _C = 125 °C		200		
Continuous source current (diode conduction) ^a		Is	200	Α	
Pulsed drain current ^b		I _{DM}	260		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	100		
Single pulse avalanche energy	L = U.I IIII	E _{AS}	500	mJ	
Maximum power dissipation ^b	T _C = 25 °C	Б	375	14/	
	T _C = 125 °C	P_{D}	125	W	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount c	R_{thJA}	40	°CAM	
Junction-to-case (drain)		R_{thJC}	0.4	°C/W	

Notes

- a. Package limited
- b. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static					•	•	•	
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		40	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	· V _{GS} , I _D = 250 μA	2.5	3.0	3.5	V	
Gate-source leakage	I _{GSS}	V _{DS} =	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	± 100	nA	
Zero gate voltage drain current		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1		
	I _{DSS}	V _{GS} = 0 V	V _{DS} = 40 V, T _J = 125 °C	1	-	50	μA	
		V _{GS} = 0 V	V _{DS} = 40 V, T _J = 175 °C	-	-	300	μΑ	
On-state drain current a	I _{D(on)}	V _{GS} = 10 V	V _{DS} ≥ 5 V	100	-	-	Α	
	, ,	V _{GS} = 10 V	I _D = 35 A	-	0.00084	0.00100		
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 35 A, T _J = 125 °C	-	-	0.00140	Ω	
	, ,	V _{GS} = 10 V	I _D = 35 A, T _J = 175 °C	ı	-	0.00164		
Forward transconductance b	9 _{fs}	V_{DS}	= 15 V, I _D = 30 A	-	196	-	S	
Dynamic ^b		•				•	ı	
Input capacitance	C _{iss}		V _{DS} = 25 V, f = 1 MHz	-	11 938	15 525	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	11 163	14 520		
Reverse transfer capacitance	C _{rss}	1			282	370		
Total gate charge ^c	Qg			ı	158	250		
Gate-source charge c	Q _{gs}	V _{GS} = 10 V V _{DS} = 20 V, I _D = 100 A		-	44	-	nC	
Gate-drain charge ^c	Q _{gd}			-	22	-		
Gate resistance	R_g	f = 1 MHz		2.70	5.44	8.20	Ω	
Turn-on delay time c	t _{d(on)}			-	16	25		
Rise time ^c	t _r	V _{DD} =	= 20 V, $R_L = 0.2 \Omega$	ı	10	17		
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 100 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$		ı	103	160	ns	
Fall time ^c	t _f			-	61	95		
Source-Drain Diode Ratings and Chara	cteristics ^b	•			•	•	L	
Pulsed current ^a	I _{SM}			-	-	260	Α	
Forward voltage	V _{SD}	I _F = 60 A, V _{GS} = 0 V		-	0.81	1.5	V	
Body diode reverse recovery time	t _{rr}	I _F = 30 A, di/dt = 100 A/μs		-	165	350	ns	
Body diode reverse recovery charge	Q _{rr}			-	530	1100	nC	
Reverse recovery fall time	ta			-	66	-		
Reverse recovery rise time	t _b			-	99	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}		-	-6.2	-	Α		

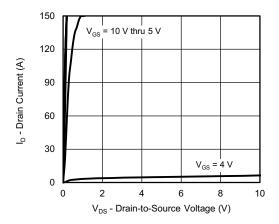
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

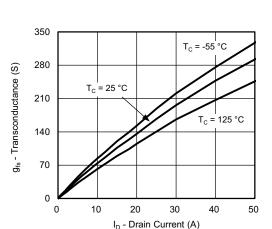
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



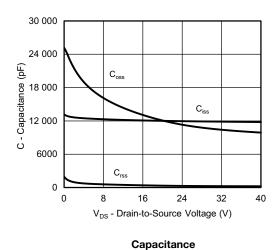
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Output Characteristics

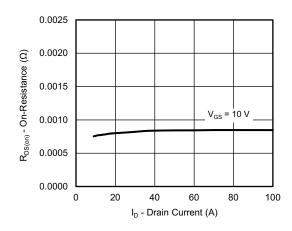


Transconductance

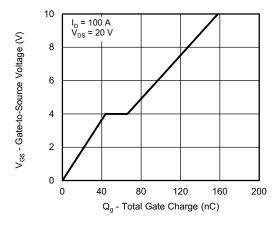


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Transfer Characteristics



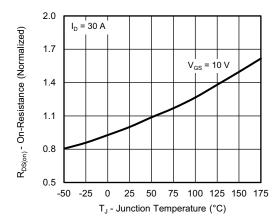
On-Resistance vs. Drain Current



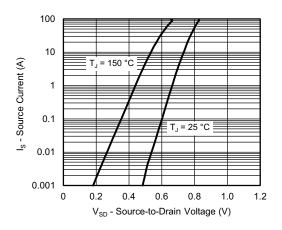
Gate Charge



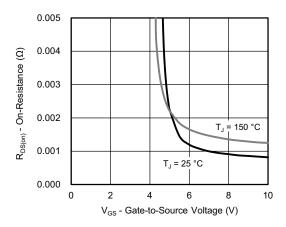
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



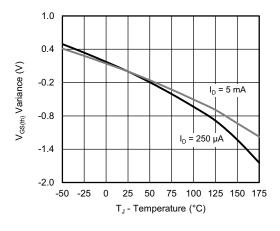
On-Resistance vs. Junction Temperature



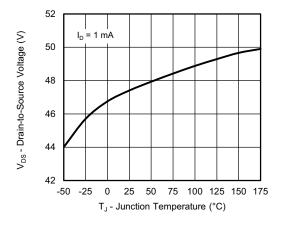
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



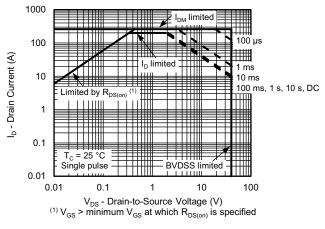
Threshold Voltage



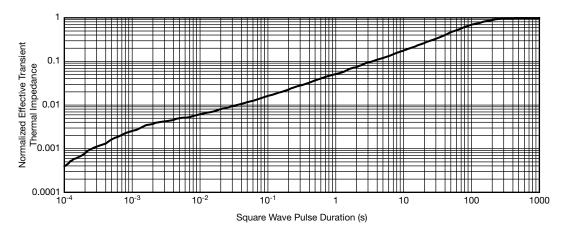
Drain Source Breakdown vs. Junction Temperature



THERMAL RATINGS ($T_A = 25$ °C, unless otherwise noted)



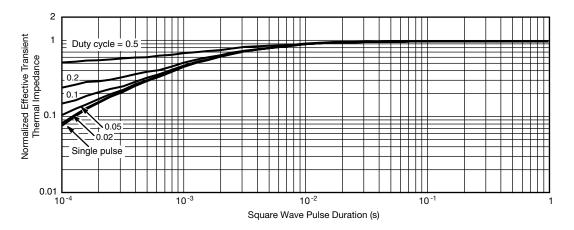
Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

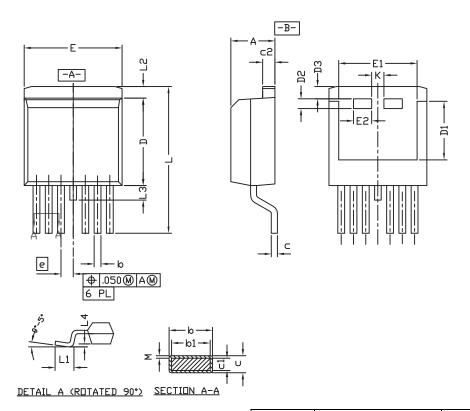
are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77738.





D²PAK (TO-263-7L) Case Outline



Notes

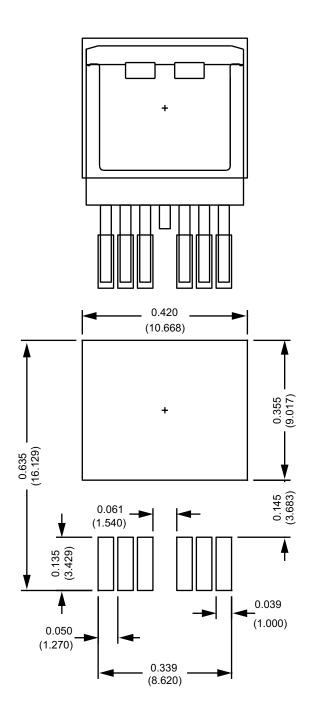
- 1. Plane B includes maximum features of heat sink tab and plastic
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils
- 3. Pin to pin coplanarity max. 4 mils
- 4. Lead thickness 25 mils
- 5. For SUM part numbers lead thickness is 24 mils to 29 mils
- 6. For reference only
- 7. Use inches as the primary measurement
- 8. This feature is only for SUM

	INCHES		MILLIMETERS		
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	0.160	0.190	4.064	4.826	
b	0.020	0.039	0.508	0.990	
b1	0.020	0.035	0.508	0.889	
c* SUB	0.012	0.018	0.305	0.457	
c* SUM	0.022	0.028	0.559	0.711	
c1	0.018	0.025	0.457	0.635	
c2	0.045	0.055	1.143	1.397	
D	0.340	0.380	8.636	9.652	
D1	0.260	0.280	6.604	7.112	
D2	0.046	0.050	1.168	1.270	
D3	0.045	0.055	1.143	1.397	
E	0.380	0.410	9.652	10.414	
E1	0.245	-	6.223	-	
E2	0.072	0.078	1.829	1.981	
е	0.050	BSC	1.27	BSC	
K	0.045	0.055	1.143	1.397	
L	0.575	0.625	14.605	15.875	
L1	0.090	0.110	2.286	2.794	
L2	0.040	0.055	1.016	1.397	
L3	0.050	0.070	1.270	1.778	
L4	0.010 BSC		0.254 BSC		
М	-	0.002	-	0.050	
ECN: T22-0410-Rev. D, 19-Sep-2022 DWG: 6006					

Revision: 19-Sep-2022 Document Number: 63782



Recommended Land Pattern D²PAK (TO-263-7L)





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